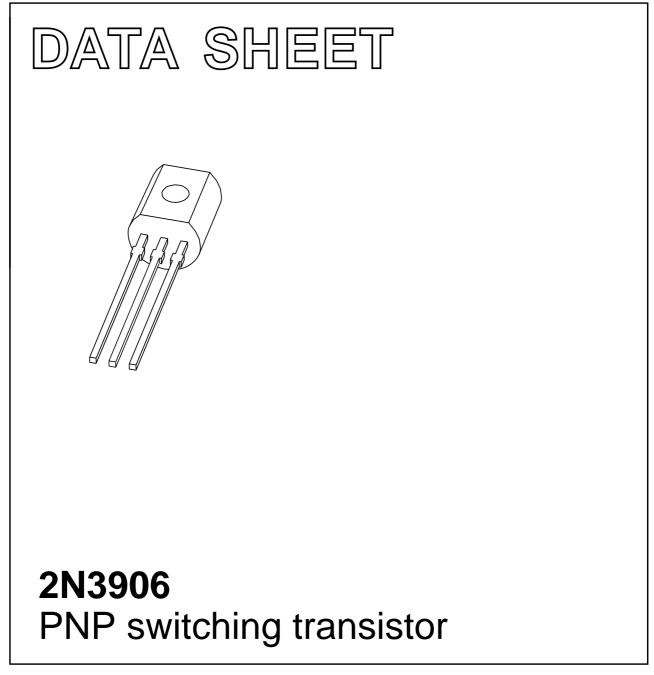
DISCRETE SEMICONDUCTORS



Product specification Supersedes data of 1999 Apr 23 2004 Oct 11



Philips Semiconductors

2N3906

FEATURES

- Low current (max. 200 mA)
- Low voltage (max. 40 V).

APPLICATIONS

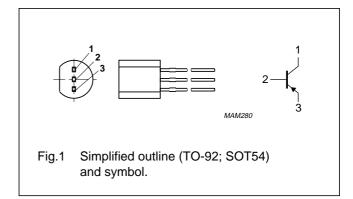
• High-speed switching in industrial applications.

DESCRIPTION

PNP switching transistor in a TO-92; SOT54 plastic package. NPN complement: 2N3904.

PINNING

PIN	DESCRIPTION	
1	collector	
2	base	
3	emitter	



ORDERING INFORMATION

TYPE NUMBER	PACKAGE			
		DESCRIPTION	VERSION	
2N3906	SC-43A	-43A plastic single-ended leaded (through hole) package; 3 leads		

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	-	-40	V
V _{CEO}	collector-emitter voltage	open base	-	-40	V
V _{EBO}	emitter-base voltage	open collector	-	-6	V
I _C	collector current (DC)		-	-200	mA
I _{CM}	peak collector current		-	-300	mA
I _{BM}	peak base current		-	-100	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$	-	500	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th(j-a)}	thermal resistance from junction to ambient	note 1	250	K/W

Note

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1. Transistor mounted on an FR4 printed-circuit board.

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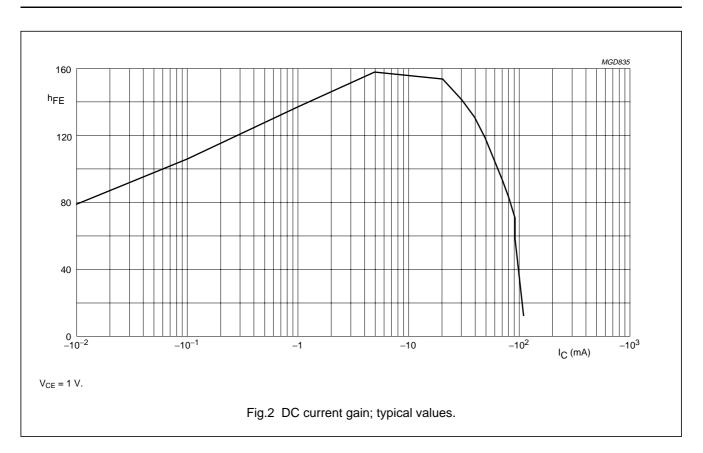
CHARACTERISTICS

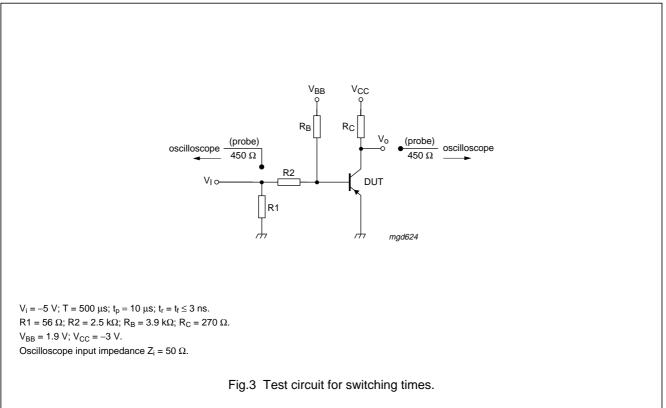
 T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I _{CBO}	collector-base cut-off current	$V_{CB} = -30 \text{ V}; \text{ I}_{\text{E}} = 0 \text{ A}$	-	-50	nA
I _{EBO}	emitter-base cut-off current	$V_{EB} = -6 \text{ V}; \text{ I}_{C} = 0 \text{ A}$	-	-50	nA
h _{FE}	DC current gain	$V_{CE} = -1$ V; note 1; see Fig.2			
		$I_{\rm C} = -0.1 {\rm mA}$	60	-	
		$I_{\rm C} = -1 \mathrm{mA}$	80	-	
		$I_{\rm C} = -10 \text{ mA}$	100	300	
		I _C = -50 mA	60	-	
		$I_{\rm C} = -100 {\rm mA}$	30	-	
V _{CEsat}	collector-emitter saturation	$I_{\rm C} = -10 \text{ mA}; I_{\rm B} = -1 \text{ mA}; \text{ note } 1$	-	-200	mV
	voltage	$I_{C} = -50 \text{ mA}; I_{B} = -5 \text{ mA}; \text{ note } 1$	-	-200	mV
V _{BEsat}	base-emitter saturation voltage	$I_{C} = -10 \text{ mA}; I_{B} = -1 \text{ mA}; \text{ note } 1$	-	-850	mV
		$I_{C} = -50 \text{ mA}; I_{B} = -5 \text{ mA}; \text{ note } 1$	-	-950	mV
C _c	collector capacitance	$V_{CB} = -5 \text{ V}; I_E = i_e = 0 \text{ A}; f = 1 \text{ MHz}$	-	4.5	pF
C _e	emitter capacitance	$I_{C} = i_{c} = 0; V_{EB} = -500 \text{ mV}; f = 1 \text{ MHz}$	-	10	pF
f _T	transition frequency	$V_{CE} = -20 \text{ V}; \text{ I}_{C} = -10 \text{ mA}; \text{ f} = 100 \text{ MHz}$	250	-	MHz
F	noise figure	$V_{CE} = -5 \text{ V}; \text{ I}_{C} = -100 \mu\text{A}; \text{ R}_{S} = 1 k\Omega;$ f = 10 Hz to 15.7 kHz	-	4	dB
Switching t	imes (between 10 % and 90 % lev	els); see Fig.3	•	•	
t _{on}	turn-on time	$I_{Con} = -10 \text{ mA}; I_{Bon} = -1 \text{ mA};$	-	65	ns
t _d	delay time	$I_{Boff} = 1 \text{ mA}$		35	ns
t _r	rise time	1	_	35	ns
t _{off}	turn-off time	1	_	300	ns
ts	storage time	1	_	225	ns
t _f	fall time	1	-	75	ns

Note

1. Pulse test: $t_p \leq 300 \ \mu s; \ \delta \leq 0.02.$

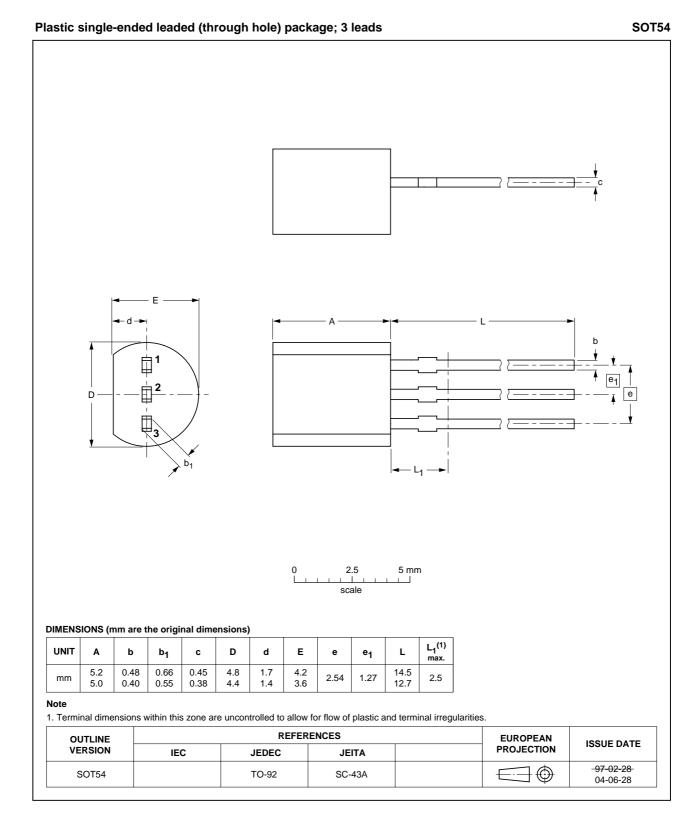




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PACKAGE OUTLINE



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DATA SHEET STATUS

LEVEL	DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾⁽³⁾	DEFINITION
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
11	Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
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Notes

- 1. Please consult the most recently issued data sheet before initiating or completing a design.
- 2. The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.
- 3. For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

DEFINITIONS

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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